

Technical Data Data Sheet N0907, Rev. - Green Products

SBRF4045CT SCHOTTKY RECTIFIER

Applications:

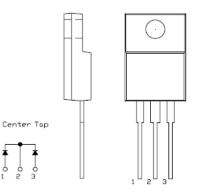
- Switching power supply •
- Converters •
- **Free-Wheeling diodes**
- **Reverse battery protection**

Features:

- 150 ℃ TJ operation •
- Center tap configuration •
- Low forward voltage drop •
- High purity, high temperature epoxy encapsulation for • enhanced mechanical strength and moisture resistance
- High frequency operation •
- Guard ring for enhanced ruggedness and long term reliability •
- This is a Pb Free Device •

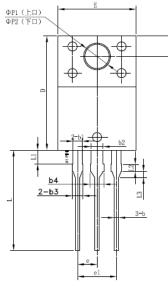
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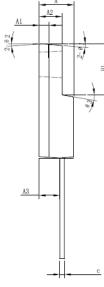
- All SMC parts are traceable to the wafer lot •
- Additional testing can be offered upon request

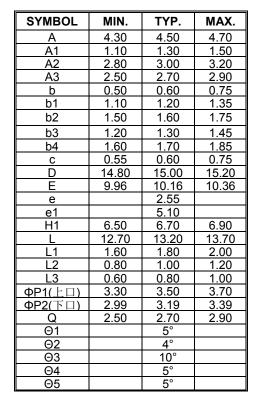


OUTLINE DRAWING

Mechanical Dimensions: In mm







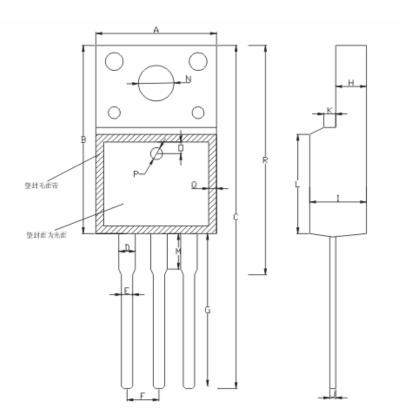
OPTION 1(HD)

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• FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



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A:10.20	± 0.50	B:15.90	±0.50	C:29.00	± 1.00	D:1.24	± 0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	± 0.05	J:0.50	± 0.05	K:1.20	± 0.20	L:8.00	± 0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	± 0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	±1.0				

OPTION 2(SR)

ITO-220AB



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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Where XXXXX is YYWWL

SBR F	= Device Type = Package type
•	
40	= Forward Current (40A)
45	= Reverse Voltage (45V)
СТ	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Ordering Information:

Device	Package	Shipping
SBRF4045CT	ITO-220AB	Europa / tuba
SBRF4045C1	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	45	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _c = 105°C, rectangular wave form	40	А
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3ms, half sine pulse	252	A



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 20 A, Pulse, T _C = 25 °C	0.65	V
(per leg) *	V_{F2}	@ 20 A, Pulse, T _C = 125 °C	0.60	V
Max. Reverse Current (per		$@V_R = rated V_R$	1.0	mA
leg) *	I _{R1}	T _C = 25 °C	1.0	ША
	1	$@V_R = rated V_R$	50.0	mA
	I _{R2}	T _C = 125 °C		
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	900	pF
(per leg)		f _{SIG} = 1MHz		
Repetitive peak reverse	IRRM	tp = 2 μs square F= 1 kHz	1	А
current				
Non-Repetitive Avalanche	Eas	T _J = 25 °C, I _{AS} = 2 A,	2	mJ
Energy		L = 1mH		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal	Р	DC eneration	1.5	°C/W
Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	1.5	-0/00
Approximate Weight	wt	-	2.0	g
Case Style		ITO-220AB		



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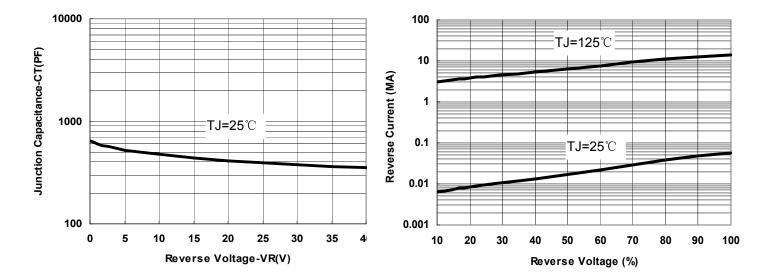




Fig.2-Typical Reverse Characteristics

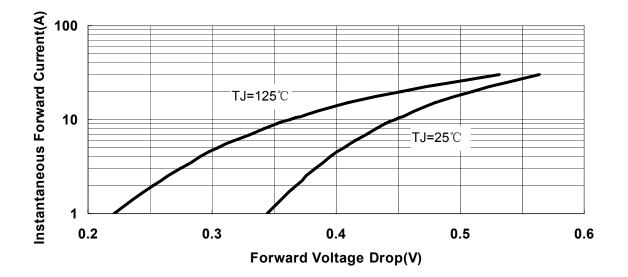


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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